24-stage frequency divider and oscillator Rev. 7 — 30 March 2016

Product data sheet

1. **General description**

The HEF4521B consists of a chain of 24 toggle flip-flops with an overriding asynchronous master reset input (MR), and an input circuit that allows three modes of operation. The single inverting stage (A2 to Y2) functions as: a crystal oscillator, an input buffer for an external oscillator or in combination with A1 as an RC oscillator. The crystal oscillator operates in Low-power mode when pins V_{SS1} and V_{DD1} are supplied via external resistors.

Each flip-flop divides the frequency of the previous flip-flop by two, consequently the HEF4521B counts up to 2²⁴ = 16777216. The counting advances on the HIGH-to-LOW transition of the clock (A2). The outputs from each of the last seven stages (2¹⁸ to 2²⁴) are available for additional flexibility.

It operates over a recommended V_{DD} power supply range of 3 V to 15 V referenced to V_{SS} (usually ground). Unused inputs must be connected to V_{DD}, V_{SS}, or another input.

Features and benefits 2.

- Low power crystal oscillator operation
- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Specified from -40 °C to +85 °C
- Complies with JEDEC standard JESD 13-B

Ordering information 3.

Table 1. Ordering information	Table 1.	Ordering	information
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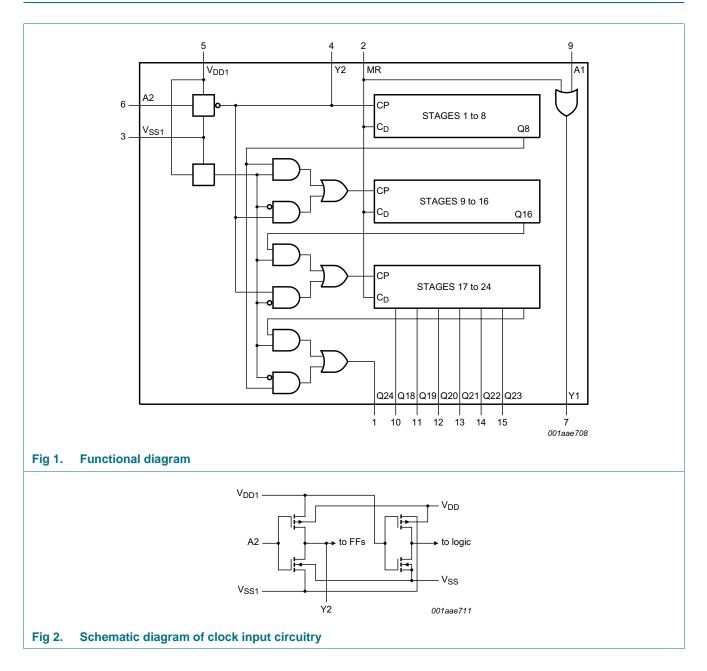
All types operate from -40 °C to +85 °C.

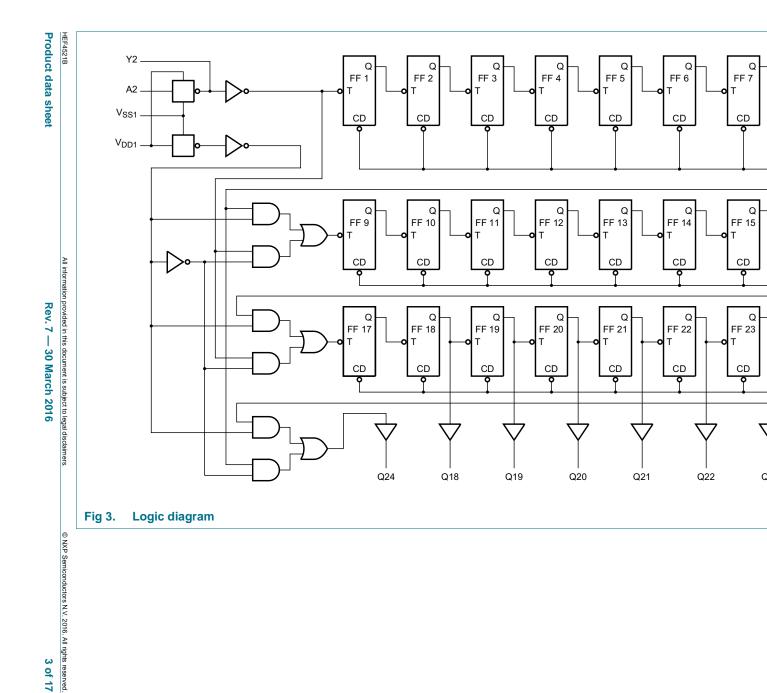
Type number	Package						
	Name	Description	Version				
HEF4521BT	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1				



24-stage frequency divider and oscillator

4. Functional diagram



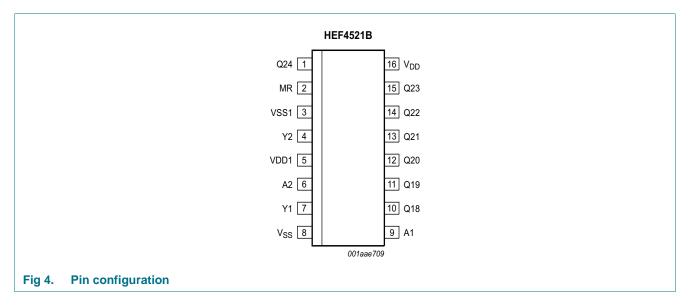


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5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description	
MR	2	master reset input	
V _{SS1}	3	ground supply voltage 1	
V _{DD1}	5	supply voltage 1	
Y1, Y2	7, 4	external oscillator connection	
V _{SS}	8	ground supply voltage	
A1, A2	9, 6	external oscillator connection	
Q18 to Q24	10, 11, 12, 13, 14, 15, 1	output	
V _{DD}	16	supply voltage	

6. Count capacity

Table 3.	Count capacity
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Output	Count capacity
Q18	2 ¹⁸ = 262144
Q19	2 ¹⁹ = 524288
Q20	2 ²⁰ = 1048576
Q21	2 ²¹ = 2097152
Q22	2 ²² = 4194304
Q23	2 ²³ = 8388608
Q24	2 ²⁴ = 16777216

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7. Functional test

A test function has been included to reduce the test time required to test all 24 counter stages. This test function divides the counter into three 8-stage sections by connecting V_{SS1} to V_{DD} and V_{DD1} to V_{SS}. 255 counts are loaded into each of the 8-stage sections in parallel via A2 (connected to Y2). All flip-flops are now at a HIGH level. The counter is now returned to the normal 24-stage in series configuration by connecting V_{SS1} to V_{SS} and V_{DD1} to V_{DD}. Entering one more pulse into input A2 causes the counter to ripple from an all HIGH state to an all LOW state.

Input	s	Contro	ol termina	ls	Outputs	Remarks
MR	A2	Y2	V _{SS1}	V _{DD1}	Q18 to Q24	
Н	L	L	V _{DD}	V _{SS}	L	counter is in three 8-stage sections in parallel mode; A2 and Y2 are interconnected (Y2 is now input); counter is reset by MR.
L	[2]	[2]	V _{DD}	V_{SS}	Н	
L	L	L	V _{SS}	V_{SS}	Н	V _{SS1} is connected to V _{SS} .
L	Н	L	V _{SS}	V_{SS}	Н	the input A2 is made HIGH.
L	Н	L	V _{SS}	V _{DD}	Н	V_{DD1} is connected to V_{DD} ; Y2 is now made floating and becomes an output; the device is now in the 2 ²⁴ mode.
L	\downarrow		V _{SS}	V_{DD}	L	counter ripples from an all HIGH state to an all LOW state.

Table 4. Functional test sequence^[1]

[1] H = HIGH voltage level; L = LOW voltage level; $\downarrow = HIGH$ to LOW transition.

[2] 255 pulses are clocked into A2, Y2. The counter advances on the LOW to HIGH transition.

8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DD}	supply voltage		-0.5	+18	V
I _{IK}	input clamping current	$V_{I} < -0.5$ V or $V_{I} > V_{DD}$ + 0.5 V	-	±10	mA
VI	input voltage		-0.5	V _{DD} + 0.5	V
I _{OK}	output clamping current	$V_{O} < -0.5$ V or $V_{O} > V_{DD} + 0.5$ V	-	±10	mA
I _{I/O}	input/output current		-	±10	mA
I _{DD}	supply current	to any supply terminal	-	±100	mA
T _{stg}	storage temperature		-65	+150	°C
T _{amb}	ambient temperature		-40	+85	°C
P _{tot}	total power dissipation	SO16 package [1]	-	500	mW
Р	power dissipation	per output	-	100	mW

[1] For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 °C.

9. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DD}	supply voltage		3	-	15	V
VI	input voltage		0	-	V _{DD}	V
T _{amb}	ambient temperature	in free air	-40	-	+85	°C
$\Delta t/\Delta V$	input transition rise and fall rate	V _{DD} = 5 V	-	-	3.75	μs/V
		V _{DD} = 10 V	-	-	0.5	μs/V
		V _{DD} = 15 V	-	-	0.08	μs/V

Table 6. Recommended operating conditions

10. Static characteristics

Table 7. Static characteristics

 $V_{SS} = 0$ V; $V_{I} = V_{SS}$ or V_{DD} unless otherwise specified.

Symbol	Parameter	Conditions	V _{DD}	T _{amb} =	−40 °C	T _{amb} =	= 25 °C	T _{amb} = 85 °C		Unit
				Min	Max	Min	Max	Min	Max	
VIH	HIGH-level input voltage	$ I_0 < 1 \ \mu A$	5 V	3.5	-	3.5	-	3.5	-	V
VIH I			10 V	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	V
VIL	LOW-level input voltage	$ I_0 < 1 \ \mu A$	5 V	-	1.5	-	1.5	-	1.5	V
			10 V	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	V
V _{OH}	HIGH-level output voltage	$ I_0 < 1 \ \mu A$	5 V	4.95	-	4.95	-	4.95	-	V
			10 V	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	V
V _{OL}	LOW-level output voltage	$ I_0 < 1 \ \mu A$	5 V	-	0.05	-	0.05	-	0.05	V
			10 V	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	V
I _{OH}	HIGH-level output current	V _O = 2.5 V	5 V	-	-1.7	-	-1.4	-	-1.1	mA
		V _O = 4.6 V	5 V	-	-0.52	-	-0.44	-	-0.36	mA
		V _O = 9.5 V	10 V	-	-1.3	-	-1.1	-	-0.9	mA
		V _O = 13.5 V	15 V	-	-3.6	-	-3.0	-	-2.4	mA
I _{OL}	LOW-level output current	$V_{O} = 0.4 V$	5 V	0.52	-	0.44	-	0.36	-	mA
		$V_{O} = 0.5 V$	10 V	1.3	-	1.1	-	0.9	-	mA
		V _O = 1.5 V	15 V	3.6	-	3.0	-	2.4	-	mA
l _l	input leakage current		15 V	-	±0.3	-	±0.3	-	±1.0	μA
I _{DD}	supply current	I _O = 0 A	5 V	-	20	-	20	-	150	μA
			10 V	-	40	-	40	-	300	μA
			15 V	-	80	-	80	-	600	μA
CI	input capacitance		-	-	-	-	7.5	-	-	pF

11. Dynamic characteristics

Table 8. Dynamic characteristics

 $V_{SS} = 0 V$; $T_{amb} = 25$ °C; for test circuits see <u>Figure 6</u>; unless otherwise specified.

Symbol	Parameter	Conditions	V_{DD}		Extrapolation formula	Min	Тур	Max	Unit
t _{PHL}	HIGH to LOW	A2 to Q18;	5 V	[1]	923 ns + (0.55 ns/pF)C _L	-	950	1900	ns
	propagation delay	see <u>Figure 5</u>	10 V		339 ns + (0.23 ns/pF)C _L	-	350	700	ns
			15 V		212 ns + (0.16 ns/pF)C _L	-	220	440	ns
		Qn to Qn + 1;	5 V		13 ns + (0.55 ns/pF)C _L	-	40	80	ns
		see <u>Figure 5</u>	10 V		4 ns + (0.23 ns/pF)C _L	-	15	30	ns
			15 V		2 ns + (0.16 ns/pF)C _L	-	10	20	ns
		MR to Qn	5 V		93 ns + (0.55 ns/pF)C _L	-	120	240	ns
			10 V		44 ns + (0.23 ns/pF)C _L	-	55	110	ns
			15 V		32 ns + (0.16 ns/pF)C _L	-	40	80	ns
		A1 to Y1;	5 V		63 ns + (0.55 ns/pF)C _L	-	90	180	ns
		see <u>Figure 5</u>	10 V		24 ns + (0.23 ns/pF)C _L	-	35	70	ns
			15 V		17 ns + (0.16 ns/pF)C _L	-	25	50	ns
PLH	LOW to HIGH	A2 to Q18;	5 V	[1]	923 ns + (0.55 ns/pF)C _L	-	950	1900	ns
	propagation delay	see <u>Figure 5</u>	10 V		339 ns + (0.23 ns/pF)C _L	-	350	700	ns
			15 V		212 ns + (0.16 ns/pF)C _L	-	220	440	ns
		Qn to Qn + 1; see <u>Figure 5</u>	5 V		13 ns + (0.55 ns/pF)C _L	-	40	80	ns
			10 V		4 ns + (0.23 ns/pF)C _L	-	15	30	ns
			15 V		2 ns + (0.16 ns/pF)C _L	-	10	20	ns
		A1 to Y1; see <u>Figure 5</u>	5 V		33 ns + (0.55 ns/pF)C _L	-	60	120	ns
			10 V		19 ns + (0.23 ns/pF)C _L	-	30	60	ns
			15 V		12 ns + (0.16 ns/pF)C _L	-	20	40	ns
ťt	transition time	Qn; see <u>Figure 5</u>	5 V	[1]	10 ns + (1.00 ns/pF)C _L	-	60	120	ns
			10 V		9 ns + (0.42 ns/pF)C _L	-	30	60	ns
			15 V		6 ns + (0.28 ns/pF)C _L	-	20	40	ns
w	pulse width	A2 HIGH;	5 V			80	40	-	ns
		minimum width; see Figure 5	10 V			40	20	-	ns
		see <u>rigule 5</u>	15 V			30	15	-	ns
		MR HIGH;	5 V			70	35	-	ns
		minimum width;	10 V			40	20	-	ns
		see Figure 5	15 V			30	15	-	ns
rec	recovery time	MR; see Figure 5	5 V			+20	-10	-	ns
			10 V			+15	-5	-	ns
			15 V			15	0	-	ns
max	maximum frequency	A1; see Figure 5	5 V			6	12	-	MHz
			10 V			12	25	-	MHz
			15 V			17	35	-	MHz

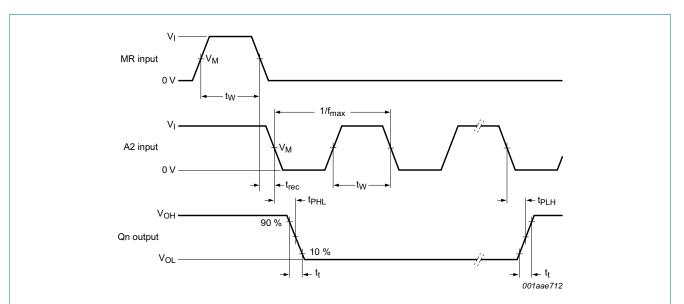
[1] The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown (C_L in pF).

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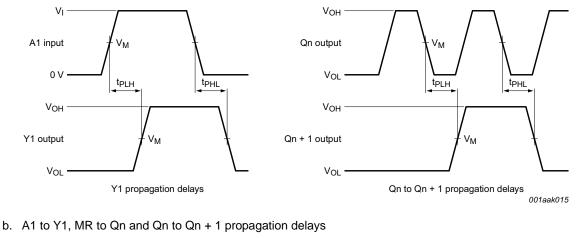
P_D can be calculated from the formulas shown. $V_{SS} = 0$ V; $t_r = t_f \le 20$ ns; $T_{amb} = 25$ °C.							
Symbol	Parameter	V _{DD}	Typical formula for P_D (μ W)	where:			
P _D	dynamic power	5 V	$P_D = 1200 \times f_i + \Sigma (f_o \times C_L) \times V_DD^2$	$f_i = input frequency in MHz,$			
dissipation		10 V	$P_D = 5100 \times f_i + \Sigma (f_o \times C_L) \times V_DD^2$	$f_o = output frequency in MHz,$			
		15 V	$P_{D} = 13050 \times f_{i} + \Sigma(f_{o} \times C_{L}) \times V_{DD}^{2}$	C_L = output load capacitance in pF,			
				V_{DD} = supply voltage in V,			
				$\Sigma(C_L \times f_o)$ = sum of the outputs.			

Table 9. Dynamic power dissipation P_D

12. Waveforms



a. Pulse widths, maximum frequency, recovery and transition times and A2 to Qn propagation delays



Measurement points are given in Table 10.

The logic levels V_{OH} and V_{OL} are typical output voltage levels that occur with the output load.

Waveforms showing measurement of dynamic characteristics Fig 5.

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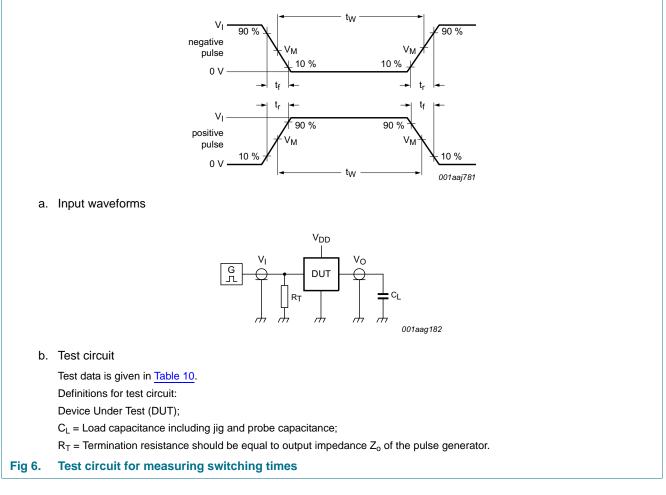


Table 10. Measurement points and test data

Supply voltage	Input	Load		
V _{DD}	VI	V _M	t _r , t _f	CL
5 V to 15 V	V _{DD}	0.5V _I	≤ 20 ns	50 pF

24-stage frequency divider and oscillator

13. Application information

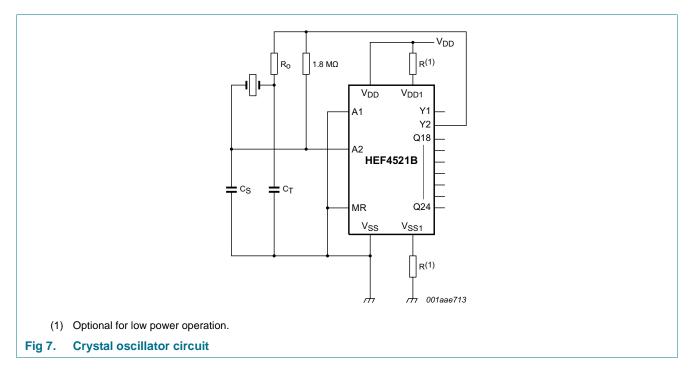


Table 11.Typical characteristics for crystal oscillatorSee Figure 7.

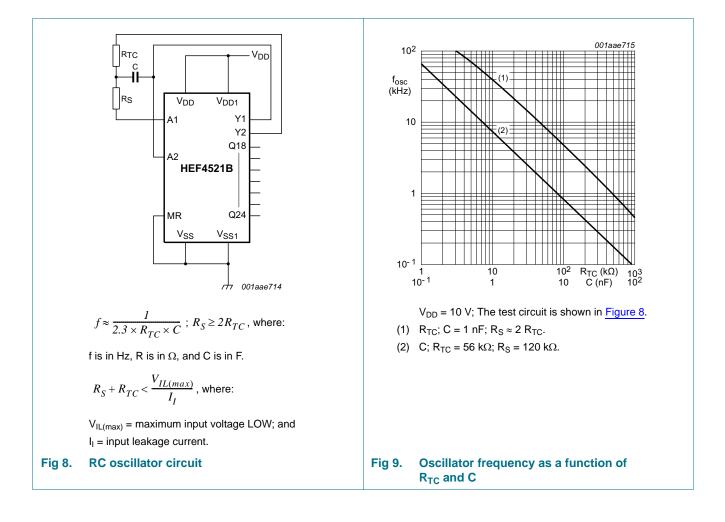
Parameter		500 kHz circuit	50 kHz circuit	Unit	
Crysta	Crystal characteristics				
	Resonance frequency	500	50	kHz	
	Crystal cut	S	Ν	-	
	Equivalent resistance; R _S	1	6.2	kΩ	
Extern	al resistor/capacitor values		•		
	R _o	47	750	kΩ	
	CT	82	82	pF	
	Cs	20	20	pF	

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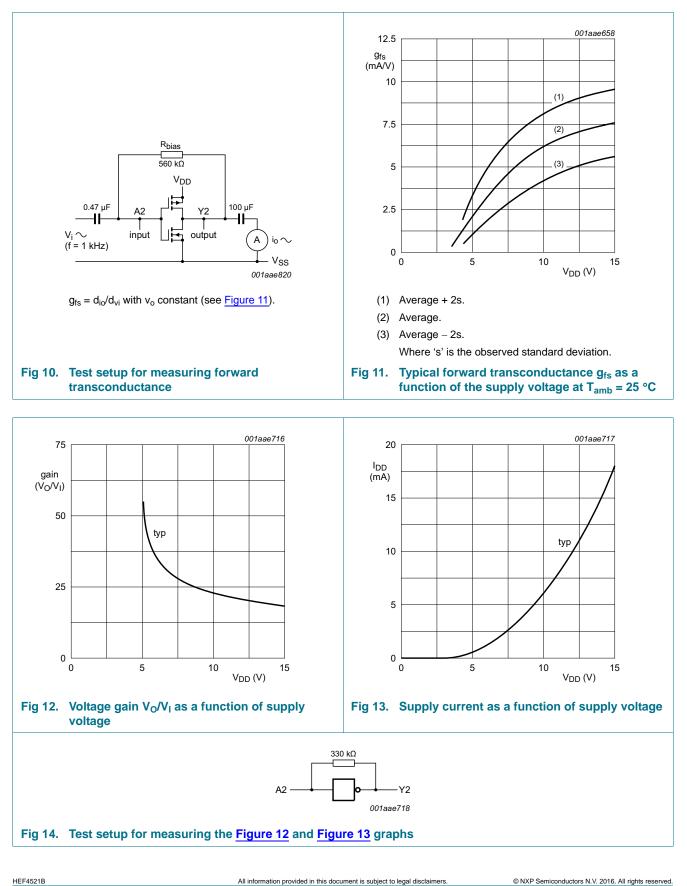
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14. Package outline

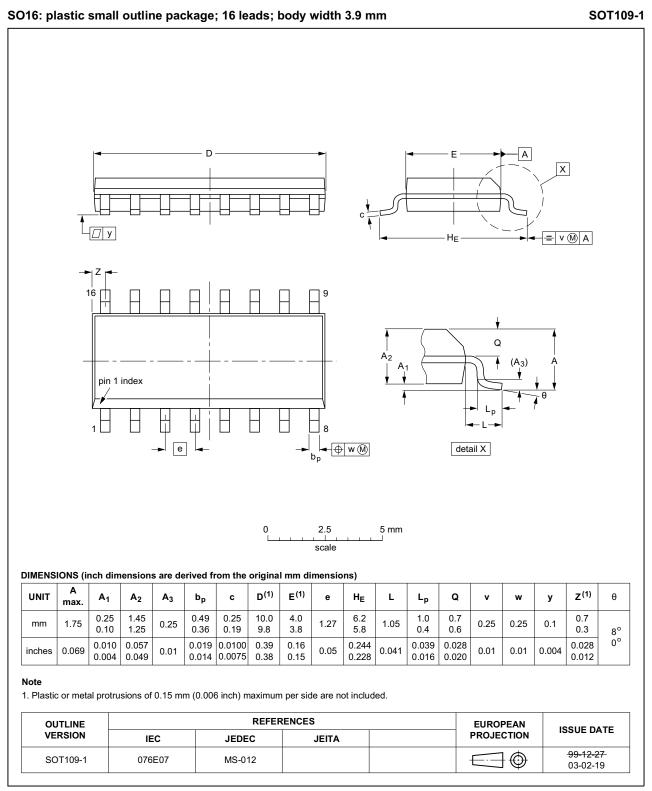


Fig 15. Package outline SOT109-1 (SO16)

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15. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
HEF4521B v.7	20160330	Product data sheet	-	HEF4521B v.6	
Modifications:	• Type number HEF4521BP (SOT38-4) removed.				
HEF4521B v.6	20111121	Product data sheet	-	HEF4521B v.5	
Modifications: • Section Applications removed					
	• <u>Table 4</u> : adde	d references to Table note [1]	and Table note [2]		
	• <u>Table 7</u> : I _{OH} n				
	 Figure 11, Figure note [1] and Figure note [3]: space between '2' and 's' remove 				
HEF4521B v.5	20091105	Product data sheet	-	HEF4521B v.4	
HEF4521B v.4	20090421	Product data sheet	-	HEF4521B_CNV v.3	
HEF4521B_CNV v.3	19950101	Product specification	-	HEF4521B_CNV v.2	
HEF4521B_CNV v.2	19950101	Product specification	-	-	

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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